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# HD74ALVC2G66

## 2-channel Analog Switch

REJ03D0177-0100Z  
(Previous ADE-205-630A (Z))  
Rev.1.00  
Jan.14.2004

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### Description

The HD74ALVC2G66 has 2-channel analog switch in an 8 pin package. Each switch section has its own enable input control (C). High-level voltage applied to C turns on the associated switch section. Applications include signal gating, chopping, modulation, or demodulation (modem), and signal multiplexing for analog to digital and digital to analog conversion systems. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

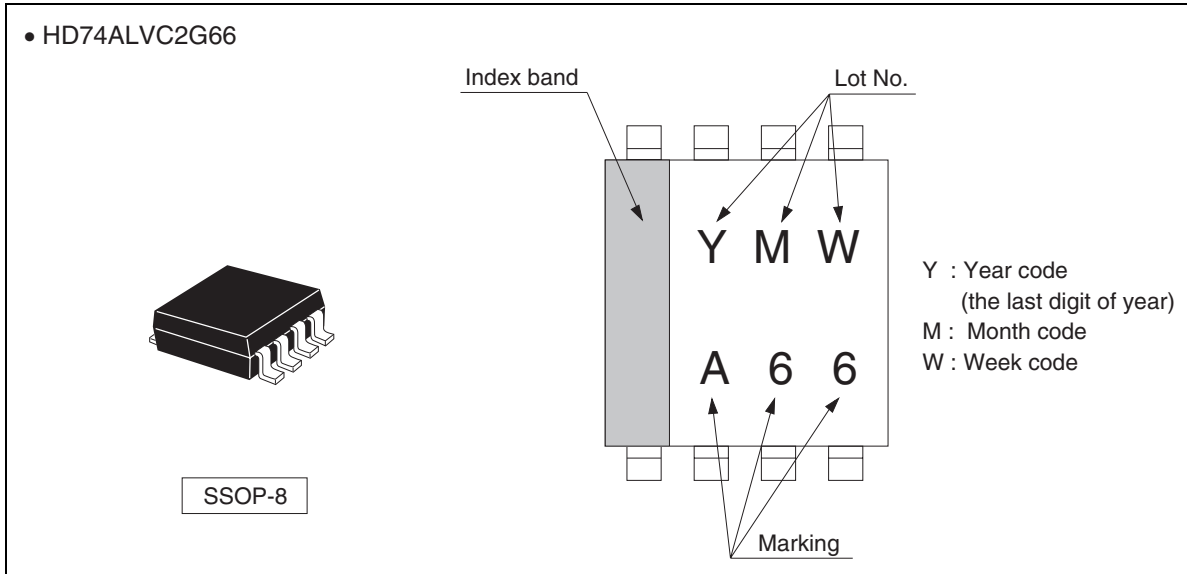
### Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Supply voltage range : 1.2 to 3.6 V  
Operating temperature range: -40 to +85°C
- All control input  $V_{IH}$  (Max.) = 3.6 V (@ $V_{CC}$  = 0 V to 3.6 V)
- Ordering Information

<b>Part Name</b>	<b>Package Type</b>	<b>Package Code</b>	<b>Package Abbreviation</b>	<b>Taping Abbreviation (Quantity)</b>
HD74ALVC2G66USE	SSOP-8 pin	TTP-8DBV	US	E (3,000 pcs/reel)

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## Outline and Article Indication

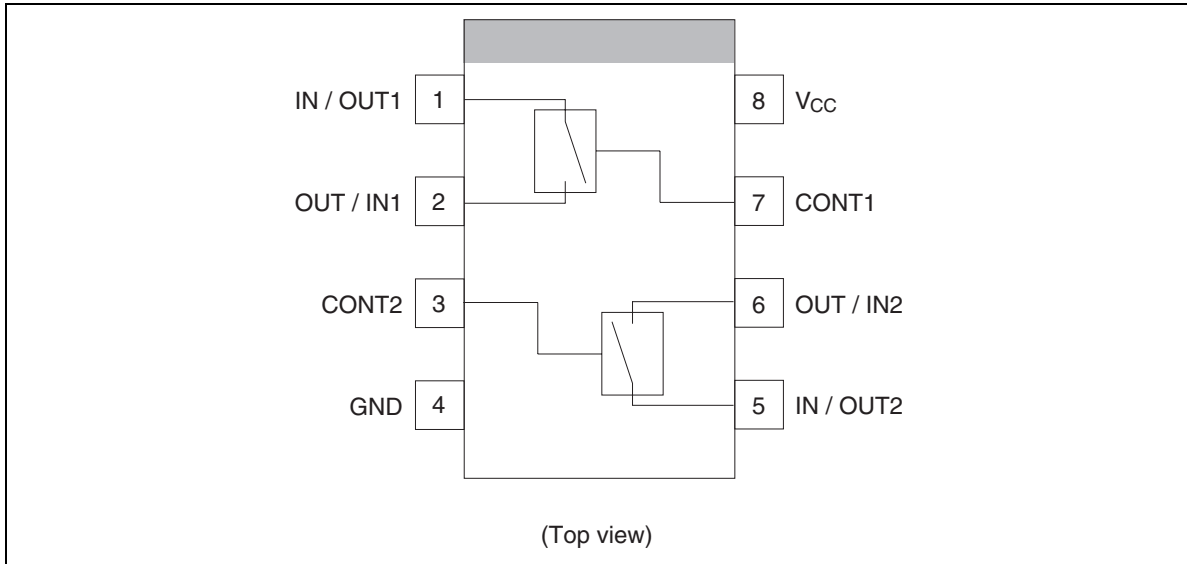


## Function Table

Control	Switch
L	OFF
H	ON

H: High level  
L: Low level

### Pin Arrangement



**Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	$V_{CC}$	-0.5 to 4.6	V	
Input voltage range <sup>*1</sup>	$V_I$	-0.5 to 4.6	V	
Output voltage range <sup>*1, 2</sup>	$V_O$	-0.5 to $V_{CC}+0.5$	V	Output : H or L
Input clamp current	$I_{IK}$	-50	mA	$V_I < 0$
Output clamp current	$I_{OK}$	$\pm 50$	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	$I_O$	$\pm 50$	mA	$V_O = 0$ to $V_{CC}$
Continuous current through $V_{CC}$ or GND	$I_{CC}$ or $I_{GND}$	$\pm 100$	mA	
Maximum power dissipation at $T_a = 25^\circ\text{C}$ (in still air) <sup>*3</sup>	$P_T$	200	mW	
Storage temperature	$T_{stg}$	-65 to 150	$^\circ\text{C}$	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. This value is limited to 4.6 V maximum.
3. The maximum package power dissipation was calculated using a junction temperature of  $150^\circ\text{C}$ .

**Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	$V_{CC}$	1.2	3.6	V	
Input voltage range	$V_I$	0	3.6	V	
Input / output voltage range	$V_{I/O}$	0	$V_{CC}$	V	
Input transition rise or fall rate	$\Delta t / \Delta v$	0	20	ns / V	$V_{CC} = 1.2$ to $2.7$ V
		0	10		$V_{CC} = 3.3 \pm 0.3$ V
Operating free-air temperature	$T_a$	-40	85	$^\circ\text{C}$	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristics

Item	Symbol	V <sub>CC</sub> (V)	Ta=25°C			Ta=-40 to 85°C			Unit	Test conditions	
			Min	Typ	Max	Min	Typ	Max			
Input voltage	V <sub>IH</sub>	1.2	—	—	—	V <sub>CC</sub> ×0.75	—	—	V	Control input only	
		1.4 to 1.6	—	—	—	V <sub>CC</sub> ×0.7	—	—			
		1.65 to 1.95	—	—	—	V <sub>CC</sub> ×0.7	—	—			
		2.3 to 2.7	—	—	—	1.7	—	—			
		3.0 to 3.6	—	—	—	2.0	—	—			
	V <sub>IL</sub>	1.2	—	—	—	—	—	V <sub>CC</sub> ×0.25			
		1.4 to 1.6	—	—	—	—	—	V <sub>CC</sub> ×0.3			
		1.65 to 1.95	—	—	—	—	—	V <sub>CC</sub> ×0.3			
		2.3 to 2.7	—	—	—	—	—	0.7			
		3.0 to 3.6	—	—	—	—	—	0.8			
On-state switch resistance	R <sub>ON</sub>	1.2	—	15	—	—	—	—	Ω	V <sub>I</sub> = 0 V, I <sub>O</sub> = 1 mA	
			—	27	—	—	—	—		V <sub>I</sub> = 1.2 V, I <sub>O</sub> = 1 mA	
		1.4	—	11	25	—	—	—		30	V <sub>I</sub> = 0 V, I <sub>O</sub> = 2 mA
			—	20	35	—	—	—		40	V <sub>I</sub> = 1.4 V, I <sub>O</sub> = 2 mA
		1.65	—	9	17	—	—	—		20	V <sub>I</sub> = 0 V, I <sub>O</sub> = 4 mA
			—	16	27	—	—	—		30	V <sub>I</sub> = 1.65 V, I <sub>O</sub> = 4 mA
		2.3	—	7	10	—	—	—		12	V <sub>I</sub> = 0 V, I <sub>O</sub> = 8 mA
			—	12	18	—	—	—		20	V <sub>I</sub> = 2.3 V, I <sub>O</sub> = 8 mA
		3.0	—	6	8.5	—	—	—		9	V <sub>I</sub> = 0 V, I <sub>O</sub> = 24 mA
			—	10	13.5	—	—	—		14.5	V <sub>I</sub> = 3.0 V, I <sub>O</sub> = 24 mA
Peak on resistance	R <sub>ON(p)</sub>	1.2	—	300	—	—	—	—	Ω	I <sub>O</sub> = 1 mA	
		1.4	—	135	250	—	—	350		I <sub>O</sub> = 2 mA	
		1.65	—	60	110	—	—	150		I <sub>O</sub> = 4 mA	
		2.3	—	19	30	—	—	35		I <sub>O</sub> = 8 mA	
		3.0	—	12	18	—	—	20		I <sub>O</sub> = 24 mA	

Electrical Characteristics (cont)

Item	Symbol	V <sub>CC</sub> (V)	Ta=25°C			Ta=-40 to 85°C			Unit	Test conditions
			Min	Typ	Max	Min	Typ	Max		
Difference of on-state resistance between switches	$\Delta R_{ON}$	1.2	—	1.0	—	—	—	—	$\Omega$	$I_O = 1 \text{ mA}$
		1.4	—	0.8	12	—	—	15		$I_O = 2 \text{ mA}$
		1.65	—	0.6	9	—	—	12		$I_O = 4 \text{ mA}$
		2.3	—	0.5	5	—	—	9		$I_O = 8 \text{ mA}$
		3.0	—	0.2	3	—	—	4		$I_O = 24 \text{ mA}$
Off-state switch leakage current	$I_{S(OFF)}$	3.6	—	—	$\pm 0.1$	—	—	$\pm 1.0$	$\mu\text{A}$	$V_{IN} = V_{CC}$ , $V_{OUT} = \text{GND}$ or $V_{IN} = \text{GND}$ , $V_O = V_{CC}$ , $V_C = V_{IL}$
On-state switch leakage current	$I_{S(ON)}$	3.6	—	—	$\pm 0.1$	—	—	$\pm 1.0$	$\mu\text{A}$	$V_{IN} = V_{CC}$ or $\text{GND}$ $V_C = V_{IH}$
Input current	$I_{IN}$	0 to 3.6	—	—	$\pm 0.1$	—	—	$\pm 1.0$	$\mu\text{A}$	$V_{IN} = 3.6 \text{ V}$ or $\text{GND}$
Quiescent supply current	$I_{CC}$	3.6	—	—	—	—	—	10	$\mu\text{A}$	$V_{IN} = V_{CC}$ or $\text{GND}$
Control input capacitance	$C_{IC}$	—	—	3.5	—	—	—	—	pF	
Switch terminal capacitance	$C_{IN/OUT}$	—	—	5.0	—	—	—	—	pF	
Feed through capacitance	$C_{IN-OUT}$	—	—	0.4	—	—	—	—	pF	

## HD74ALVC2G66

### Switching Characteristics

( $T_a = -40$  to  $85^\circ\text{C}$ )

$V_{CC} = 1.2$  V

Item	Symbol	Min	Typ	Max	Unit	Test conditions	FROM (Input)	TO (Output)
Propagation delay time <sup>*1</sup>	$t_{PLH}$ $t_{PHL}$	—	0.4	—	ns	$C_L = 15$ pF	IN/OUT or OUT/IN	OUT/IN or IN/OUT
Enable time	$t_{ZH}$ $t_{ZL}$	—	5.0	—	ns	$C_L = 15$ pF	C	IN/OUT or OUT/IN
Disable time	$t_{HZ}$ $t_{LZ}$	—	4.5	—	ns	$C_L = 15$ pF	C	IN/OUT or OUT/IN

$V_{CC} = 1.5 \pm 0.1$  V

Item	Symbol	Min	Typ	Max	Unit	Test conditions	FROM (Input)	TO (Output)
Propagation delay time <sup>*1</sup>	$t_{PLH}$ $t_{PHL}$	—	—	0.3	ns	$C_L = 15$ pF	IN/OUT or OUT/IN	OUT/IN or IN/OUT
Enable time	$t_{ZH}$ $t_{ZL}$	2.0	—	6.0	ns	$C_L = 15$ pF	C	IN/OUT or OUT/IN
Disable time	$t_{HZ}$ $t_{LZ}$	2.0	—	6.0	ns	$C_L = 15$ pF	C	IN/OUT or OUT/IN

$V_{CC} = 1.8 \pm 0.15$  V

Item	Symbol	Min	Typ	Max	Unit	Test conditions	FROM (Input)	TO (Output)
Propagation delay time <sup>*1</sup>	$t_{PLH}$ $t_{PHL}$	—	—	0.48	ns	$C_L = 30$ pF	IN/OUT or OUT/IN	OUT/IN or IN/OUT
Enable time	$t_{ZH}$ $t_{ZL}$	1.5	—	5.0	ns	$C_L = 30$ pF	C	IN/OUT or OUT/IN
Disable time	$t_{HZ}$ $t_{LZ}$	1.5	—	5.0	ns	$C_L = 30$ pF	C	IN/OUT or OUT/IN

## HD74ALVC2G66

### Switching Characteristics (cont)

$$V_{CC} = 2.5 \pm 0.2 \text{ V}$$

Item	Symbol	Min	Typ	Max	Unit	Test conditions	FROM (Input)	TO (Output)
Propagation delay time <sup>*1</sup>	t <sub>PLH</sub> t <sub>PHL</sub>	—	—	0.35	ns	C <sub>L</sub> = 30 pF	IN/OUT or OUT/IN	OUT/IN or IN/OUT
Enable time	t <sub>ZH</sub> t <sub>ZL</sub>	1.0	—	4.0	ns	C <sub>L</sub> = 30 pF	C	IN/OUT or OUT/IN
Disable time	t <sub>HZ</sub> t <sub>LZ</sub>	1.0	—	4.0	ns	C <sub>L</sub> = 30 pF	C	IN/OUT or OUT/IN

$$V_{CC} = 3.3 \pm 0.3 \text{ V}$$

Item	Symbol	Min	Typ	Max	Unit	Test conditions	FROM (Input)	TO (Output)
Propagation delay time <sup>*1</sup>	t <sub>PLH</sub> t <sub>PHL</sub>	—	—	0.3	ns	C <sub>L</sub> = 30 pF	IN/OUT or OUT/IN	OUT/IN or IN/OUT
Enable time	t <sub>ZH</sub> t <sub>ZL</sub>	1.0	—	3.0	ns	C <sub>L</sub> = 30 pF	C	IN/OUT or OUT/IN
Disable time	t <sub>HZ</sub> t <sub>LZ</sub>	1.0	—	3.0	ns	C <sub>L</sub> = 30 pF	C	IN/OUT or OUT/IN

Note: 1. The propagation delay time is calculated by the RC (on-resistance and load capacitance) time constant.

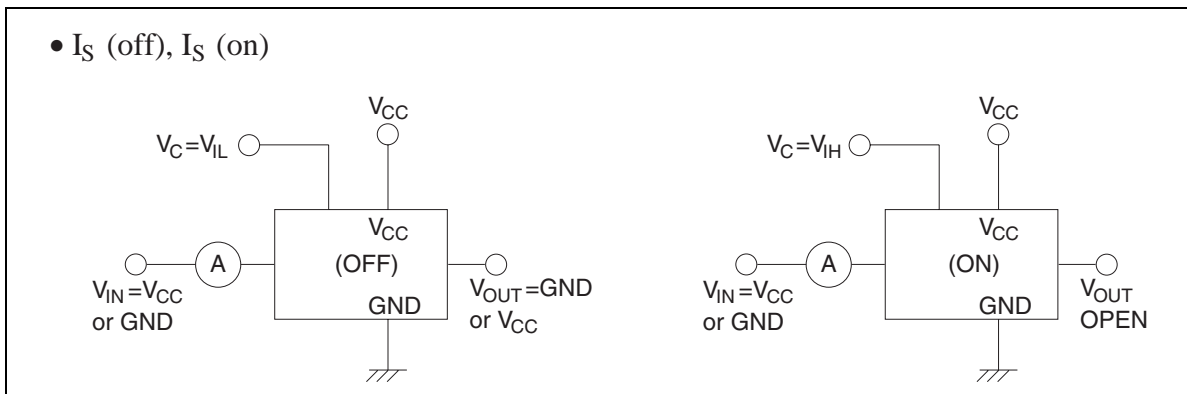
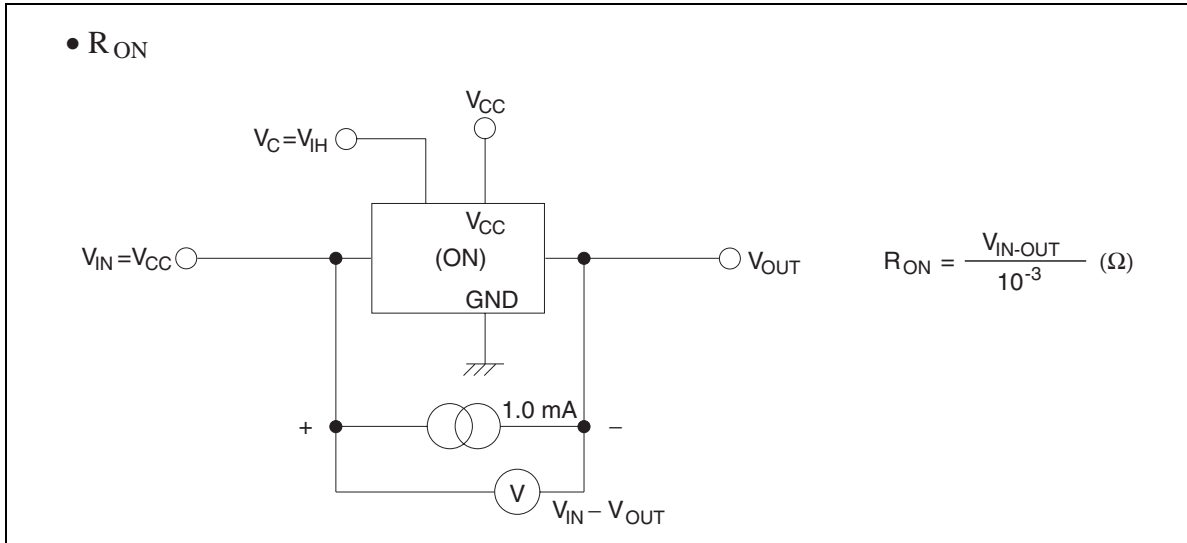
### Operating Characteristics

(T<sub>a</sub> = 25°C)

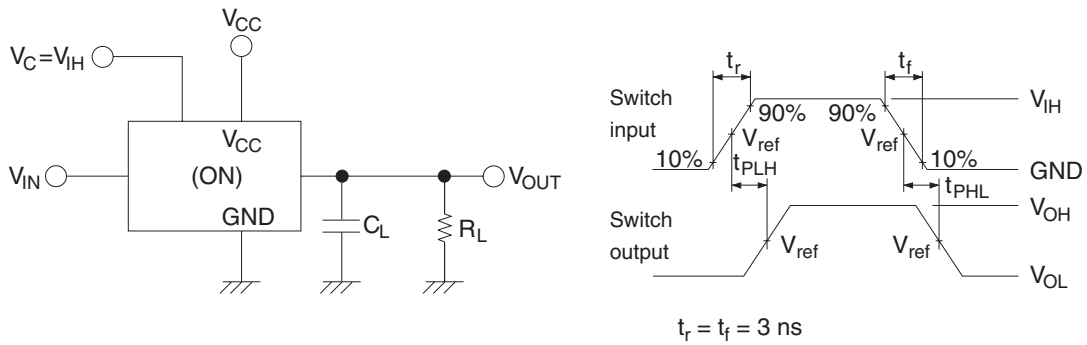
Item	Symbol	V <sub>CC</sub> (V)	Min	Typ	Max	Unit	Test conditions
Power dissipation capacitance	C <sub>PD</sub>	1.5	—	4.5	—	pF	f = 10 MHz
		1.8	—	4.5	—		
		2.5	—	5.0	—		
		3.3	—	6.0	—		



Test Circuit



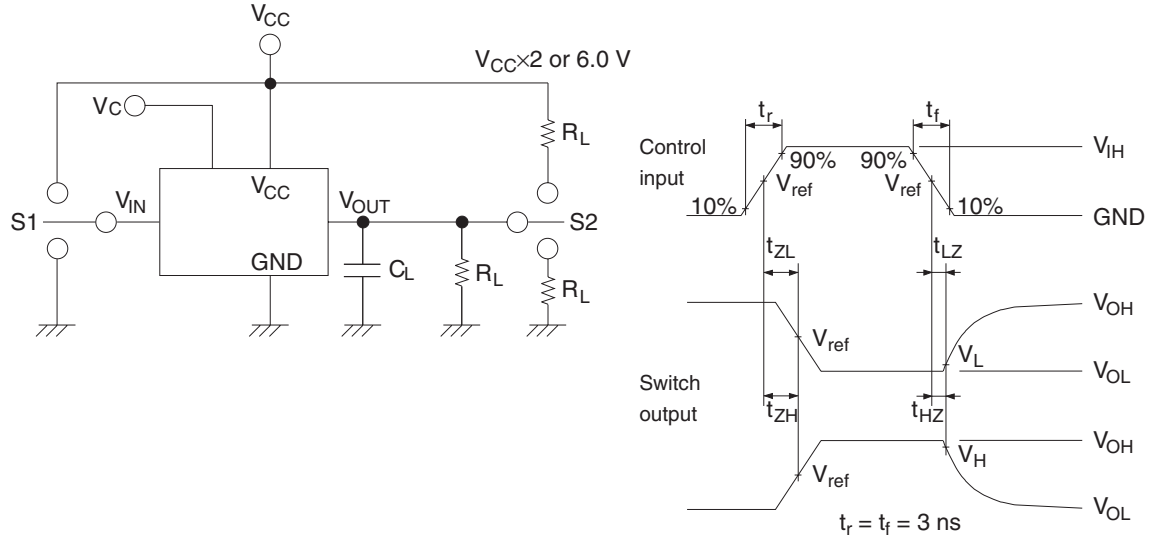
•  $t_{PLH}$ ,  $t_{PHL}$



Symbol	$V_{CC} = 1.2 \text{ V},$ $1.5 \pm 0.1 \text{ V}$	$V_{CC} = 1.8 \pm 0.15 \text{ V}$	$V_{CC} = 2.5 \pm 0.2 \text{ V},$ $3.3 \pm 0.3 \text{ V}$
$R_L$	2.0 k $\Omega$	1.0 k $\Omega$	500 $\Omega$
$C_L$	15 pF	30 pF	30 pF

Symbol	$V_{CC} = 1.2 \text{ V},$ $1.5 \pm 0.1 \text{ V},$ $1.8 \pm 0.15 \text{ V}$	$V_{CC} = 2.5 \pm 0.2 \text{ V}$	$V_{CC} = 3.3 \pm 0.3 \text{ V}$
$t_r / t_f$	2.0 ns	2.5 ns	2.5 ns
$V_{IH}$	$V_{CC}$	$V_{CC}$	2.7 V
$V_{ref}$	50%	50%	1.5 V

•  $t_{ZH}, t_{ZL} / t_{HZ}, t_{LZ}$

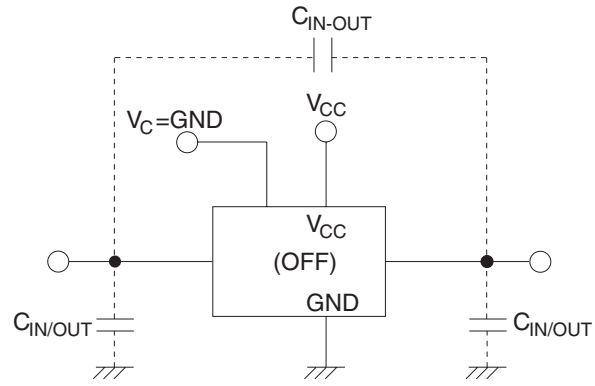


	S1		S2	
Symbol	$V_{CC} = 1.2 \text{ V},$ $1.5 \pm 0.1 \text{ V},$ $1.8 \pm 0.15 \text{ V},$ $2.5 \pm 0.2 \text{ V}$	$V_{CC} = 3.3 \pm 0.3 \text{ V}$	$V_{CC} = 1.2 \text{ V},$ $1.5 \pm 0.1 \text{ V},$ $1.8 \pm 0.15 \text{ V},$ $2.5 \pm 0.2 \text{ V}$	$V_{CC} = 3.3 \pm 0.3 \text{ V}$
$t_{HZ} / t_{ZH}$	$V_{CC}$	$V_{CC}$	GND	GND
$t_{LZ} / t_{ZL}$	GND	GND	$V_{CC} \times 2$	6.0 V

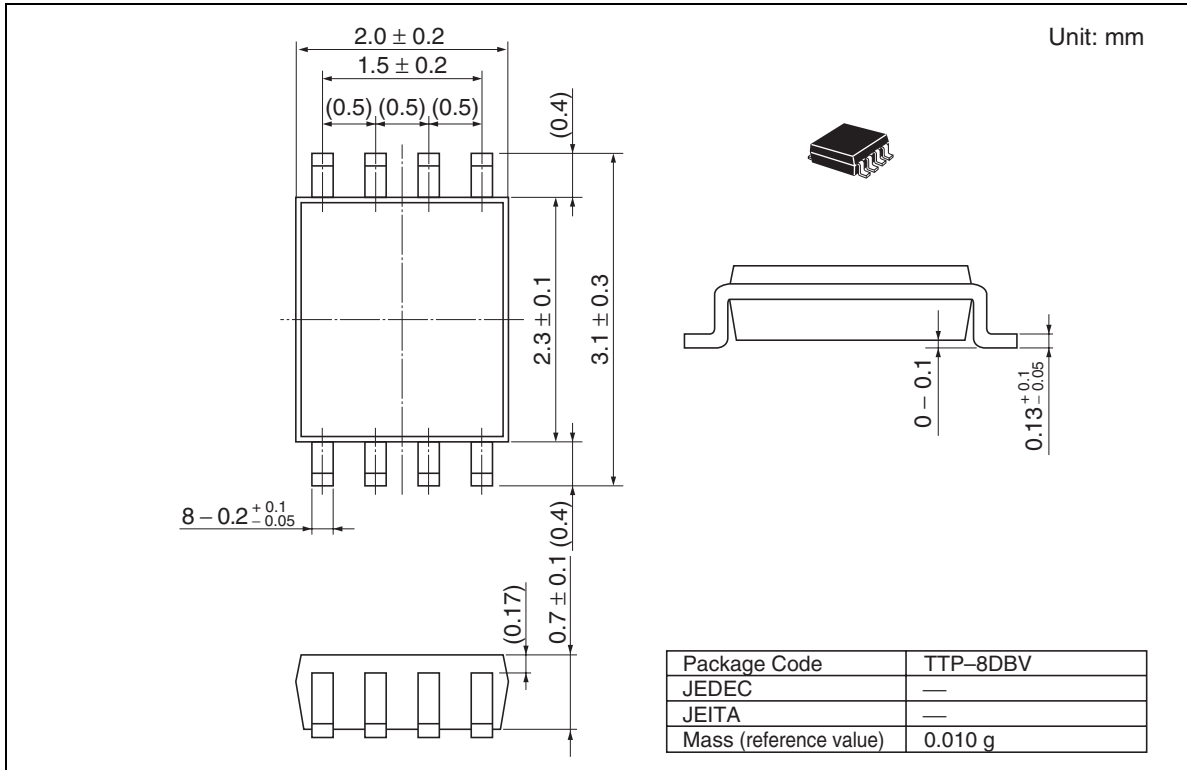
Symbol	$V_{CC} = 1.2 \text{ V},$ $1.5 \pm 0.1 \text{ V}$	$V_{CC} = 1.8 \pm 0.15 \text{ V}$	$V_{CC} = 2.5 \pm 0.2 \text{ V},$ $3.3 \pm 0.3 \text{ V}$
$R_L$	2.0 k $\Omega$	1.0 k $\Omega$	500 $\Omega$
$C_L$	15 pF	30 pF	30 pF

Symbol	$V_{CC} = 1.2 \text{ V},$ $1.5 \pm 0.1 \text{ V}$	$V_{CC} = 1.8 \pm 0.15 \text{ V}$	$V_{CC} = 2.5 \pm 0.2 \text{ V}$	$V_{CC} = 3.3 \pm 0.3 \text{ V}$
$t_r / t_f$	2.0 ns	2.0 ns	2.5 ns	2.5 ns
$V_{IH}$	$V_{CC}$	$V_{CC}$	$V_{CC}$	2.7 V
$V_{ref}$	50%	50%	50%	1.5 V
$V_H / V_L$	$V_H = V_{OH} - 0.1 \text{ V}$ $V_L = V_{OL} + 0.1 \text{ V}$	$V_H = V_{OH} - 0.15 \text{ V}$ $V_L = V_{OL} + 0.15 \text{ V}$	$V_H = V_{OH} - 0.15 \text{ V}$ $V_L = V_{OL} + 0.15 \text{ V}$	$V_H = V_{OH} - 0.3 \text{ V}$ $V_L = V_{OL} + 0.3 \text{ V}$

- $C_{IN/OUT}$ ,  $C_{IN-OUT}$



Package Dimensions



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Tel: <86> (21) 6472-1001, Fax: <86> (21) 6415-2952

**Renesas Technology Singapore Pte. Ltd.**

1, Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632  
Tel: <65> 6213-0200, Fax: <65> 6278-8001

